

# BAS21AHT1G

## Low Leakage Switching Diode

### Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

### MAXIMUM RATINGS

Symbol	Rating	Value	Unit
$V_R$	Continuous Reverse Voltage	250	Vdc
$V_{RRM}$	Repetitive Peak Reverse Voltage	250	Vdc
$I_F$	Peak Forward Current	200	mAdc
$I_{FM(surge)}$	Peak Forward Surge Current	625	mAdc

### THERMAL CHARACTERISTICS

Symbol	Characteristic	Max	Unit
$P_D$	Total Device Dissipation FR-5 Board, (Note 1) $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	200 1.57	mW mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	635	°C/W
$T_J, T_{stg}$	Junction and Storage Temperature Range	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

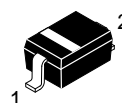
1. FR-5 Minimum Pad



**ON Semiconductor®**

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## LOW LEAKAGE SWITCHING DIODE



**SOD-323  
CASE 477  
STYLE 1**

### MARKING DIAGRAM



AA = Device Code  
M = Date Code\*  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation may vary depending upon manufacturing location.

### ORDERING INFORMATION

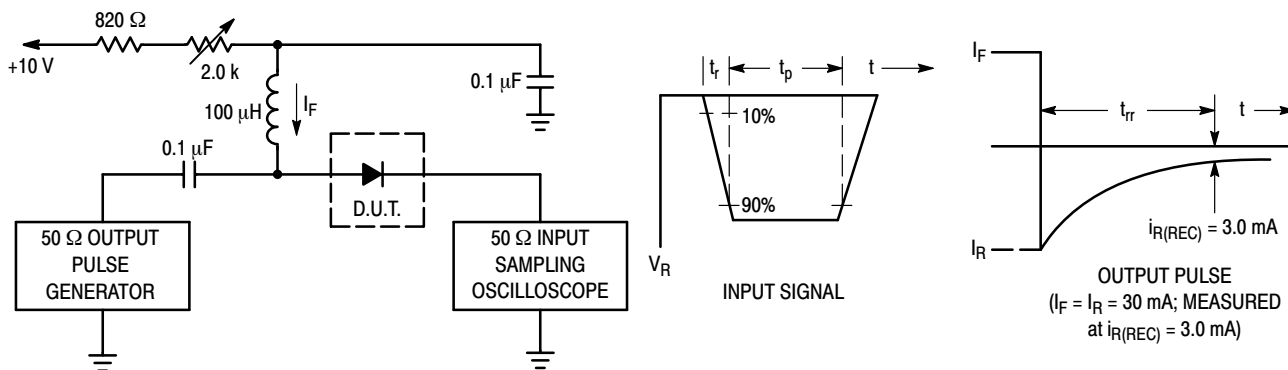
Device	Package	Shipping†
BAS21AHT1G	SOD-323 (Pb-Free)	3000/Tape & Reel
NSVBAS21AHT1G	SOD-323 (Pb-Free)	3000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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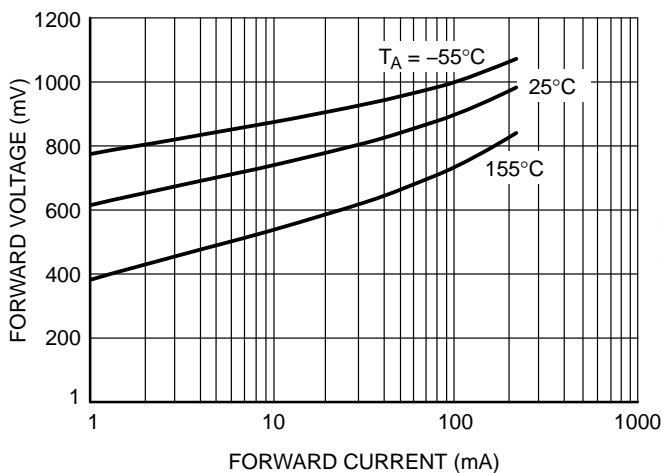
## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
<b>OFF CHARACTERISTICS</b>					
Reverse Voltage Leakage Current ( $V_R = 200\text{ Vdc}$ ) ( $V_R = 200\text{ Vdc}$ , $T_J = 150^\circ\text{C}$ )	$I_R$	-	-	40 100	nAdc $\mu\text{Adc}$
Reverse Breakdown Voltage ( $I_{BR} = 100\ \mu\text{Adc}$ )	$V_{(BR)}$	250	-	-	Vdc
Forward Voltage ( $I_F = 100\ \text{mA}$ ) ( $I_F = 200\ \text{mA}$ )	$V_F$	- -	- -	1000 1250	mV
Diode Capacitance ( $V_R = 0$ , $f = 1.0\ \text{MHz}$ )	$C_D$	-	-	5.0	pF
Reverse Recovery Time ( $I_F = I_R = 30\ \text{mA}$ , $R_L = 100\ \Omega$ )	$t_{rr}$	-	50	-	ns

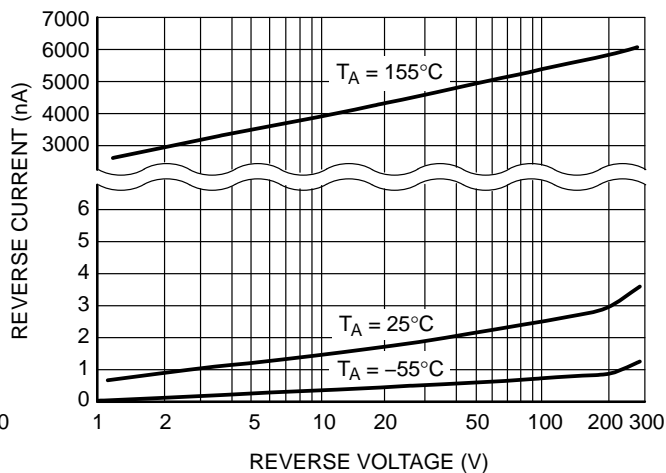


- Notes: 1. A 2.0 kΩ variable resistor adjusted for a Forward Current ( $I_F$ ) of 30 mA.  
 2. Input pulse is adjusted so  $I_{R(\text{peak})}$  is equal to 30 mA.  
 3.  $t_p \gg t_{rr}$

**Figure 1. Recovery Time Equivalent Test Circuit**



**Figure 2. Forward Voltage**

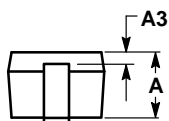
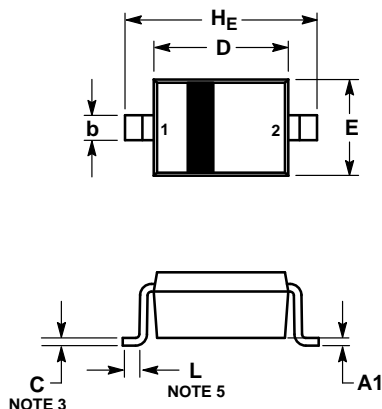


**Figure 3. Reverse Leakage**

# BAS21AHT1G

## PACKAGE DIMENSIONS

SOD-323  
CASE 477-02  
ISSUE H



NOTES:

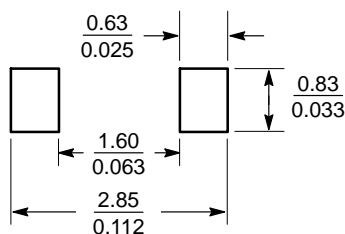
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. LEAD THICKNESS SPECIFIED PER L/F DRAWING WITH SOLDER PLATING.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
5. DIMENSION L IS MEASURED FROM END OF RADIUS.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.80	0.90	1.00	0.031	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A3	0.15 REF			0.006 REF		
b	0.25	0.32	0.4	0.010	0.012	0.016
C	0.089	0.12	0.177	0.003	0.005	0.007
D	1.60	1.70	1.80	0.062	0.066	0.070
E	1.15	1.25	1.35	0.045	0.049	0.053
L	0.08			0.003		
HE	2.30	2.50	2.70	0.090	0.098	0.105


STYLE 1:

1. CATHODE
2. ANODE

### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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